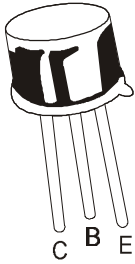


PNP SILICON POWER SWITCHING TRANSISTOR

2N3867



**TO-39
Metal Can Package**

Designed for High Speed, Medium Current Switching and High Frequency Amplifier Applications

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	VALUE	UNITS
Collector Emitter Voltage	V_{CEO}	40	V
Collector Base Voltage	V_{CBO}	40	V
Emitter Base Voltage	V_{EBO}	4.0	V
Collector Current - Continuous	I_C	3.0	A
Peak		10	A
Base Current	I_B	0.5	A
Power Dissipation@ $T_c=25^\circ\text{C}$	P_D	6.0	W
Derate Above 25°C		34.3	mW/ $^\circ\text{C}$
Power Dissipation@ $T_a=25^\circ\text{C}$	P_D	1.0	W
Derate Above 25°C		5.71	mW/ $^\circ\text{C}$
Operating And Storage Junction Temperature Range	T_j, T_{stg}	- 65 to +200	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Junction to Case	$R_{th(j-c)}$	29	$^\circ\text{C/W}$
Junction to Ambient in free air	$R_{th(j-a)}$	175	$^\circ\text{C/W}$

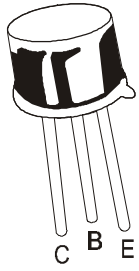
ELECTRICAL CHARACTERISTICS ($T_c=25^\circ\text{C}$ unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNITS
Collector Emitter Sustaining Voltage	$*V_{CEO(sus)}$	$I_C=20\text{mA}, I_B=0$	40		V
Collector Base Voltage	V_{CBO}	$I_C=100\mu\text{A}, I_E=0$	40		V
Emitter Base Voltage	V_{EBO}	$I_E=100\mu\text{A}, I_C=0$	4.0		V
Collector Cut Off Current	I_{CEX}	$V_{CE}=40\text{V}, V_{BE(off)}=2\text{V}$		1.0	μA
Collector Cut Off Current	I_{CBO}	$V_{CB}=40\text{V}, I_E=0, T_c=150^\circ\text{C}$		150	μA
DC Current Gain	$*h_{FE}$	$I_C=500\text{mA}, V_{CE}=1\text{V}$ $I_C=1.5\text{A}, V_{CE}=2\text{V}$ $I_C=2.5\text{A}, V_{CE}=3\text{V}$ $I_C=3\text{A}, V_{CE}=5\text{V}$	50 40 25 20	200	
Collector Emitter Saturation Voltage	$*V_{CE(Sat)}$	$I_C=500\text{mA}, I_B=50\text{mA}$ $I_C=1.5\text{A}, I_B=150\text{mA}$ $I_C=2.5\text{A}, I_B=250\text{mA}$		0.50 0.75 1.30	V
Base Emitter Saturation Voltage	$*V_{BE(Sat)}$	$I_C=500\text{mA}, I_B=50\text{mA}$ $I_C=1.5\text{A}, I_B=150\text{mA}$ $I_C=2.5\text{A}, I_B=250\text{mA}$	0.9	1.0 1.4 2.0	V

***Pulse Test: Pulse Width $\leq 300\text{ms}$, Duty Cycle $\leq 2\%$**

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ELECTRICAL CHARACTERISTICS ($T_c=25^\circ\text{C}$ unless specified otherwise)

DYNAMIC CHARACTERISTICS

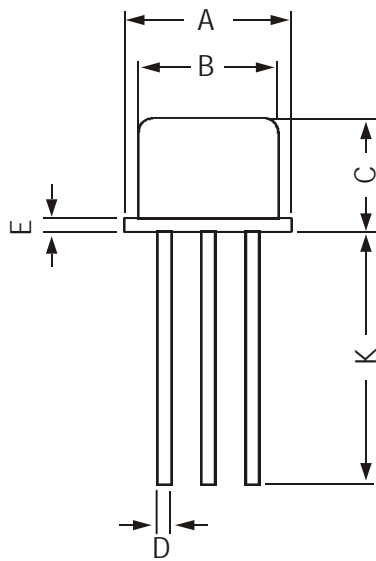
DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNITS
Current Gain Bandwidth Product	** f_T	$I_C=100\text{mA}, V_{CE}=5\text{V}, f=20\text{MHz}$	60		MHz
Output Capacitance	C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=0.1\text{MHz}$		120	pF
Input Capacitance	C_{ib}	$V_{EB}=3\text{V}, I_C=0, f=0.1\text{MHz}$		1000	pF

SWITCHING CHARACTERISTICS

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNITS
Delay Time	t_d	$V_{CC}=30\text{V}, V_{BE(off)}=0, I_C=1.5\text{A}, I_{B1}=150\text{mA}$		35	ns
Rise Time	t_r			65	ns
Storage Time	t_s	$V_{CC}=30\text{V}, I_C=1.5\text{A}, I_{B1}=I_{B2}=150\text{mA}$		325	ns
Fall Time	t_f			75	ns

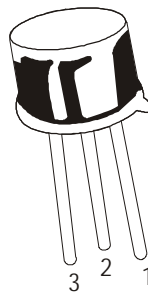
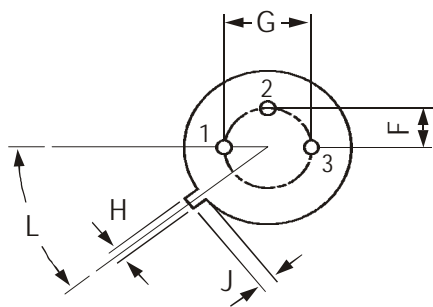
** $f_T = h_{fe} \cdot f_{test}$

TO-39 Metal Can Package



DIM	MIN	MAX
A	8.50	9.39
B	7.74	8.50
C	6.09	6.60
D	0.40	0.53
E	—	0.88
F	2.41	2.66
G	4.82	5.33
H	0.71	0.86
J	0.73	1.02
K	12.70	—
L	42 DEG	48 DEG

All dimensions are in mm



PIN CONFIGURATION

- 1. EMITTER
- 2. BASE
- 3. COLLECTOR

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-39	500 pcs/polybag	540 gm/500 pcs	3" x 7.5" x 7.5"	20K	17" x 15" x 13.5"	32K	40 kgs

Disclaimer

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